2   capacitors 2 and transistors 2 and (planarization) and ((conformal or contour) adj (passivation or overcoat)) and planarization and (gate adj 11:e52)   10:e570, JPO; DERWENT   11:e62)   20:e570, JPO; DERWENT   10:e570, JPO; JPO; DERWENT   10:e570, JPO; JPO; DERWENT   10:e570, JPO; JPO; DERWENT   10:e570, JPO; JPO; JPO; JPO; JPO; JPO; JPO; JPO;	L Number	Hits	Search Text	DB	Time stamp
(planarization) and ((conformal or contour) adj (passivation or overcoat)) and planarization and (gate adj lines2)   11:00   12:21		<del> </del>	annaitants and transistants and	HCDAM.	2004/08/05
contour) adj (passivation or overcoat) and planarization and (gate adj DERWENT 11:e82]   26764900.pn.   26764	1				
DERMENT				· ·	12:21
11ne   22   6764900.pn.   2074/08/04   11:46   2074/08/04   11:46   2074/08/04   11:46   2074/08/04   11:46   2074/08/04   11:46   2074/08/04   11:48   2074/08/04   2074/08				EPO; JPO;	
2 6764900.pn. and (four or "4") USPAT; US-PGUB; EPO, JPO; DERWENT US-PGUB; EPO, JPO; DERWENT US-PGUB; EPO, JPO; DERWENT; US-PGUB; EPO, JPO; DE			overcoat)) and planarization and (gate adj	DERWENT	
2 6764900.pn. and (four or "4") USPAT; US-PGUB; EPO, JPO; DERWENT US-PGUB; EPO, JPO; DERWENT US-PGUB; EPO, JPO; DERWENT; US-PGUB; EPO, JPO; DE			line\$2)		
	_	2		IICDAT.	2004/08/04
2   6764900.pn. and (four or "4")   EPO; JPO; DERWINT USPAT; US-PGFUB; EPO; JPO; JPO; DERWINT USPAT; US-PGFUB; EPO; JPO; JPO; JPO; JPO; JPO; JPO; JPO; J		-	0/04300.pm.		1
2   6764900.pn. and (four or "4")   USPAT; US-PGPUB; EPO; JPO; DERWENT transistor\$3)   USPAT; US-PGPUB; EPO; JPO; DERWENT US-PGPUB; EPO; JPO					11:46
2   6764900.pn. and (four or "4")   USPAT; US-PGPUB; EPO; JPO; DEWENT USPAT; US-PGPUB; EPO; JPO; JPO; DEWENT USPAT; US-PGPUB; EPO; JPO; JPO; DEWENT USPAT; US-PGPUB; EPO; JPO; JPO; JPO; JPO; JPO; JPO; JPO; J	1	ļ		EPO; JPO;	
				DERWENT	
	l <u>-</u>	2	6764900.pn, and (four or "4")	USPAT:	2004/08/04
Comparison of the comparison		_	(2002 02 )	· ·	1
DERMENT   CAPACITO					11.1/
0 6764900.pn. and (four or "4" near5   USPAT;   11:48   EPO; JPO;   DERWENT   USPAT;   USPA					
transistor\$3   US-PEPUB;   EPO, JPO; DERWENT   USPAT; US-PEPUB;   EPO, JPO; DERWENT   USPAT; USU4040404				DERWENT	
- 0 6764900.pn. and (four or "4" near10 USPAT; USPA	-	0	6764900.pn. and (four or "4" near5	USPAT;	2004/08/04
- 0 6764900.pn. and (four or "4" near10 USPAT; USPA				US-PGPUB:	11:48
0   6764900.pn. and (four or "4" near10   USPAT: US-PGFUB; EPO; UPO; DERWENT USPAT:				•	=====
- 0 6764900.pn. and (four or "4" near10 USPAT; US-PCPUB; EPO; JPO; DERWENT USPAT; US-P					
transistor\$3)    transistor\$3    comparison   comparison		_			
- 0 6764900.pn. and ((four ) adj	-	0		USPAT;	2004/08/04
- 0 6764900.pn. and ((four ) adj			transistor\$3)	US-PGPUB;	11:48
DERMENT USPAT: U			, ,	EPO: JPO:	
- 0 6764900.pn. and ((four ) adj				4	
(transistor)		_	(7(4000 mm and //Farm ) - 4		2004/08/04
- 0 6764900.pn. and (four adj transistor) USPAT; US-PGPUB; EPO; JPO; DERWENT US-PGPUB; PEO; JPO; DERWENT US-PGPUB;	_	1		1 '	,
- 0 6764900.pn. and (four adj transistor)  - 2 6764900.pn. and ((6764900.pn. and (four or "4" near10 transistor))  - 2 6764900.pn. and ((6764900.pn. and (four USPAT; US-PGPUB; EPO; JPO; DERWENT USPAT; US-PGPUB; EPO; JPO; DERWENT US-PGPUB; EPO; JPO; DERWE			(transistor))	•	11:51
- 0 6764900.pn. and (four adj transistor)  - 2 6764900.pn. and ((6764900.pn. and (four or "4" near10 transistor))  - 2 6764900.pn. and ((6764900.pn. and (four USPAT; US-PGPUB; EPO; JPO; DERWENT USPAT; US-PGPUB; EPO; JPO; DERWENT US-PGPUB; EPO; JPO; DERWE				EPO; JPO;	
- 0 6764900.pn. and (four adj transistor) USPAT; US-PGPUB; EPC; JPO; DERWENT USPAT; US-PGPUB; EPC; JPO; DERWENT USPAT; US-PGPUB; US-PGPU					
US-PGPUB;   EPO; JPO; DERWENT   USPAT;   USPAT	l _	1	6764900 pp and (four adi transistor)		2004/08/04
EPO; JPO; DERWENT USPAT; 2004/08/04 USP-GPUB; 11:56 EPO; JPO; DERWENT USPAT; 2004/08/04 USP-GPUB; 11:56 EPO; JPO; DERWENT USPAT; 2004/08/04 USP-GPUB; 11:57 EPO; JPO; DERWENT USPAT; 2004/08/04 USP-GPUB; 11:57 EPO; JPO; DERWENT USPAT; 2004/08/04 USP-GPUB; EPO; JPO; DERWENT USPAT; 2004/08/04 USPAT; 2004/08/0			oversoorbii: and (rour ad) cransiscory		
- 2 6764900.pn. and ((6764900.pn. and (four or "4" near10 transistors)3)) transistor)  - 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj					11:23
2 6764900.pn. and ((6764900.pn. and (four or "4" nearl0 transistors)) transistor)  - 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj tran				EPO; JPO;	
Or "4" near10 transistor;   US-PGPUB;   EPO; JPO;   DERWENT   USPAT;				DERWENT	
Or "4" near10 transistor;   US-PGPUB;   EPO; JPO;   DERWENT   USPAT;	_	2	6764900.pn. and ((6764900.pn. and (four	USPAT;	2004/08/04
- 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj transistor and (planarization adj layer)  - 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0					
DERWENT USPAT; 2004/08/04 11:57 EPG; JPO; DERWENT USPAT; US-PGPUB; EPG; JPO; DERWENT USPAT; U	i		or i modific clambib colfo,, clambib col,	i e	11.00
- 0 6764900.pn. and ("4" adj transistor)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj transistor and (planarization) and (conformal adj pasewent (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and ("4" adj transistor and ("5004/08/04")  - 1 1 438/155,200,239,241,256,279,393,399.ccls.  - 1 2 1 2 1004/08/04  - 1 2 2 0 0 4/08/04  - 1 2 2 0 0 4/08/04  - 1 2 2 0 0 4/08/04  - 1 2 2 0 0 4/08/04  - 1 2 2 0 0 4/08/04  - 1 2 2 0					
US-PGPUB; EPO; JPO; DERWENT USPAT; US-PGPUB; EFO; JPO; DERWENT USPAT; US-PGPUB; DERWENT US			5754000	ŀ	
- 0 6764900.pn. and ("4" adj transistors)	] -	0	6764900.pn. and ("4" adj transistor)		
- 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and (four adj transistors)  - 0 6764900.pn. and (four adj transistor and (four adj transistor)  - 0 6764900.pn. and (four adj transistors)  - 0 6764900.pn. and (four adj transis		1		US-PGPUB;	11:57
- 0 6764900.pn. and ("4" adj transistors)  - 0 6764900.pn. and (four adj transistor and (planarization) and (conformal adj passivation)  - 0 6764900.pn. and (four adj transistors)  - 0 6764900.pn. and (four adj transistor and (four adj transistor)  - 0 6764900.pn. and (four adj transistors)  - 0 6764900.pn. and (four adj transis				EPO; JPO;	
- 0 6764900.pn. and ("4" adj transistors)					
US-PGPUB; EPO; JPO; DERWENT	_		6764900 nn and /"A" add transistors)		2004/09/04
- 0 6764900.pn. and (four adj transistors)  - 0 6764900.pn. and (four adj transistors)  - 3 capacitor and transistor and (planarization adj layer) and ((conformal or conform\$3) adj (passivation adj layer) DERWENT (planarization adj layer) DERWENT (planarization adj layer)  - 3 capacitor and transistor and (planarization adj layer) DERWENT (planarization adj layer)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 438/155,200,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and capacitor	. —		o 704900.pii. aiid ( 4 adj claiisiscois)		1
- 0 6764900.pn. and (four adj transistors)  - 3 capacitor and transistor and (planarization adj layer) and ((conformal adj passivation adj layer))  - 3 capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 6 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 7 6 6 438/155,200,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 8 7 8 8 8 9 9 9 9 9 9 9 9 9 9 9 9 9 9 9					11:5/
- 0 6764900.pn. and (four adj transistors)  - 3 capacitor and transistor and (planarization adj layer) and ((conformal or conform\$3) adj (passivation adj layer) DERWENT USPAT; 2004/08/04 12:10  - 3 capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 capacitor and transistor and (planarization) and (conformal adj passivation)  - 6 capacitor and transistor and (planarization) and (conformal adj passivation)  - 7 capacitor and transistor and (planarization) and (conformal adj passivation)  - 8 capacitor and transistor and (planarization) and (conformal adj passivation)  - 9 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)  - 2 capacitor and transistor and (conformal adj passivation)  - 3 capacitor and transistor and (conformal adj passivation)  - 4 capacitor and transistor and (conformal adj passivation)  - 5 capacitor and transistor and (conformal adj passivation)  - 6 capacitor and transistor and (conformal adj passivation)  - 7 capacitor and transistor and (conformal adj passivation)  - 8 capacitor and transistor and (conformal adj passivation)  - 9 capacitor and transistor and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)  - 1 capacitor and transistor and (conformal adj passivation)					
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- 3 capacitor and transistor and (planarization adj layer) and ((conformal or conform\$3) adj (passivation adj layer))  - 3 capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 6 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 7 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 8 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 9 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)				US-PGPUB:	111:57
- 3 capacitor and transistor and (planarization adj layer) and (conformal or conform\$3) adj (passivation adj layer) DERWENT (USPAT; USPAT; USP				1	
- 3 capacitor and transistor and (planarization adj layer) and ((conformal or conform\$\$\frac{1}{3}\$) adj (passivation adj layer) DERWENT (planarization adj layer) and (conformal adj passivation adj layer)  - 3 capacitor and transistor and (planarization adj layer) DERWENT (planarization) and (conformal adj passivation)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 6 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 7 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 8 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 9 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 2 6 7 7 7 8 7 8 7 8 7 8 7 8 7 8 7 8 7 8 7					
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or conform\$3) adj (passivation adj layer))  capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  4 capacitor and transistor and (planarization) and (conformal adj passivation)  4 capacitor and transistor and (planarization) and (conformal adj passivation)  5 dash[155,200,256,279,393,399.ccls.]  6 dash[155,200,256,279,393,399.ccls.]  7 dash[155,200,239,241,256,279,393,399.ccls.]  8 and capacitor and transistor and (planarization) and (conformal adj passivation)  9 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  2 double depth (planarization) and (conformal adj passivation)  1 dash[155,200,239,241,256,279,393,399.ccls.]  2 double depth (planarization) and (conformal adj passivation)  3 double depth (planarization) and (conformal adj passivation)  4 dash[155,200,239,241,256,279,393,399.ccls.]  4 dash[155,200,239,241,256,279,393,399.ccls.]	-	] 3		1	
or conform\$3) adj (passivation adj layer))  capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  4 capacitor and transistor and (planarization) and (conformal adj passivation)  4 capacitor and transistor and (planarization) and (conformal adj passivation)  5 dash[155,200,256,279,393,399.ccls.]  6 dash[155,200,256,279,393,399.ccls.]  7 dash[155,200,239,241,256,279,393,399.ccls.]  8 and capacitor and transistor and (planarization) and (conformal adj passivation)  9 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  1 dash[155,200,239,241,256,279,393,399.ccls.]  2 dout/08/04			(planarization adj layer) and ((conformal	US-PGPUB;	12:10
layer)     Capacitor and transistor and   (planarization adj layer)   Adjusted to the component of the com				EPO; JPO;	Į i
- 3 capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)  - 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 5 capacitor and transistor and (planarization) and (conformal adj passivation)  - 6 capacitor and transistor and (planarization) and (conformal adj passivation)  - 7 capacitor and transistor and (planarization) and (conformal adj passivation)  - 8 capacitor and transistor and (planarization) and (conformal adj passivation)  - 9 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) (planarization) and (conformal adj passivation)  - 1 capacitor and transistor and (planarization) (planariz		1			
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- 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 0 438/155,200,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls.  - 2 2004/08/04					14:18
- 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 0 438/155,200,256,279,393,399.ccls. and USPAT; 2004/08/04 - 0 438/155,200,256,279,393,399.ccls. and USPAT; 2004/08/04 - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04			adj passivation adj layer)	EPO; JPO;	
- 4 capacitor and transistor and (planarization) and (conformal adj passivation)  - 0 438/155,200,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04				DERWENT	
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passivation)  Passivation  Pass		]			
- 0 438/155,200,256,279,393,399.ccls. and USPAT; 2004/08/04 capacitor and transistor and (planarization) and (conformal adj passivation) - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04 and capacitor and transistor and (planarization) and (conformal adj passivation) - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04					1 +3.73
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capacitor and transistor and (planarization) and (conformal adj passivation)  1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04 and capacitor and transistor and (planarization) and (conformal adj passivation)  1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04					
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passivation)  1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04 and capacitor and transistor and (planarization) and (conformal adj passivation)  1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04					
- 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04 and capacitor and transistor and (planarization) and (conformal adj passivation) - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04		_			]
and capacitor and transistor and US-PGPUB; (planarization) and (conformal adj passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04					0004/00/04
(planarization) and (conformal adj EPO; JPO; passivation)  - 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04	<del>-</del> :	1 1			
(planarization) and (conformal adj EPO; JPO; passivation) DERWENT 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04		'		US-PGPUB;	14:36
passivation) 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04		1		EPO; JPO;	
- 1 438/155,200,239,241,256,279,393,399.ccls. USPAT; 2004/08/04	,	1			1
	_	1			2004/08/04
I and capacitor and transistor and IUS-PGPUR: 114.43	~	1 -		· ·	1
		1		US-PGPUB;	14:43
(planarization) and ((conformal or EPO; JPO;				EPO; JPO;	
contour) adj passivation)   DERWENT		·	contour) adj passivation)	DERWENT	

			T	
-	0	250/59,214.1,370.09,580.ccls. and	USPAT;	2004/08/04
		capacitor and transistor and	US-PGPUB;	14:44
		(planarization) and ((conformal or	EPO; JPO;	
		contour) adj passivation)	DERWENT	
-	0	257/295,312.ccls. and capacitor and	USPAT;	2004/08/04
		transistor and (planarization) and	US-PGPUB;	14:45
		((conformal or contour) adj passivation)	EPO; JPO;	
			DERWENT	
-	4	capacitor and transistor and	USPAT;	2004/08/04
		(planarization) and ((conformal or	US-PGPUB;	14:46
		contour) adj passivation)	EPO; JPO;	
		,	DERWENT	
[ <b>-</b> ]	4	capacitor and transistor and	USPAT;	2004/08/04
		(planarization) and ((conformal or	US-PGPUB;	14:47
		contour) adj passivation) and	EPO; JPO;	
		planarization	DERWENT	
_	2	capacitor and transistor and	USPAT;	2004/08/04
		(planarization) and ((conformal or	US-PGPUB;	14:56
		contour) adj passivation) and	EPO; JPO;	1
		planarization and (gate adj line)	DERWENT	
_	2	capacitor and transistor and	USPAT;	2004/08/05
-	۷	(planarization) and ((conformal or	US-PGPUB;	12:20
		contour) adj (passivation or	EPO; JPO;	12.20
		overcoat))and planarization and (gate adj	DERWENT	
			DEKMENI	
	2	line)	USPAT;	2004/08/04
_	۷	capacitor and transistor and	US-PGPUB;	14:59
		(planarization) and ((conformal or	EPO; JPO;	14:59
		contour) adj (passivation or	1 ' '	
		overcoat)) and (gate adj line)	DERWENT	2004/08/04
-	2	capacitor and transistor and	USPAT;	15:00
		(planarization) and ((conformal or	US-PGPUB;	12:00
		contour) adj (passivation or	EPO; JPO;	
		overcoat))and (gate adj line) and (common	DERWENT	
	_	adj line)	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	1 2004/00/04
-	2	6060714.pn.	USPAT;	2004/08/04
			US-PGPUB;	17:13
			EPO; JPO;	
			DERWENT	1 0004/00/01
-	0	6060714.pn. and gray-photolithography	USPAT;	2004/08/04
			US-PGPUB;	17:14
	•		EPO; JPO;	
			DERWENT	, , ,
-	0	6060714.pn. and (gray-tone adj	USPAT;	2004/08/04
		photolithography)	US-PGPUB;	17:15
]			EPO; JPO;	
			DERWENT	